

UNISONIC TECHNOLOGIES CO., LTD

UTR2304

Advance

HALF-BRIDGE DRIVER

DESCRIPTION

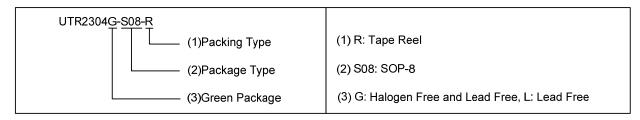
The **UTR2304** is a high voltage, high speed power MOSFET and IGBT driver with independent high-side and low-side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output driver features a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side configuration which operates up to 600V.

FEATURES

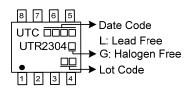
- * Floating channel designed for bootstrap operation
- * Fully operational to 600V
- * Tolerant to negative transient voltage, dV/dt immune
- * Gate drive supply range from 10V to 20V
- * Undervoltage lockout
- * 3.3V, 5V, and 15V input logic compatible
- * Cross-conduction prevention logic
- * Matched propagation delay for both channels
- * Internal 100 ns deadtime
- * Outputs in phase with inputs
- * RoHS compliant

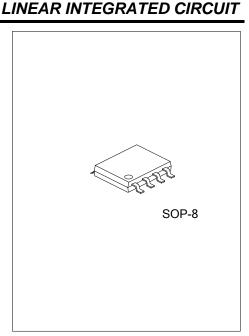
ORDERING INFORMATION

Ordering Number		Deskare	Packing	
Lead Free	Halogen Free	Halogen Free Package		
UTR2304L-S08-R	UTR2304G-S08-R	SOP-8	Tape Reel	



MARKING

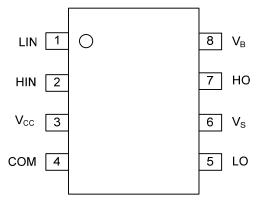




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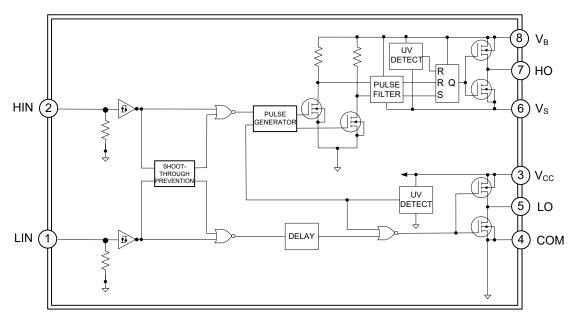
PIN CONFIGURATION



PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	LIN	Logic input for low-side gate driver output (LO), out of phase
2	HIN	Logic input for high-side gate driver output (HO), in phase
3	V _{cc}	Low-side and logic fixed supply
4	COM	Low-side return
5	LO	Low-side gate drive output
6	Vs	High-side floating supply return
7	НО	High-side gate drive output
8	VB	High-side floating supply

BLOCK DIAGRAM





■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	SYMBOL RATINGS	
High-Side Floating Absolute Voltage	V _B	-0.3 ~ 625	V
High-Side Floating Supply Offset Voltage	Vs	V _B -25 ~ V _B +0.3	V
High-Side Floating Output Voltage	V _{HO}	V _S -0.3 ~ V _S +0.3	V
Low-Side and logic Fixed Supply Voltage	V _{cc}	-0.3 ~ 25	V
Low-Side Output Voltage	V _{LO}	-0.3 ~ V _{CC} +0.3	V
Logic Input Voltage (HIN &LIN)	V _{IN}	-0.3 ~ V _{CC} +0.3	V
Allowable Offset Supply Voltage Transient	dVs/dt	50	V
Power Dissipation	PD	1	W
Maximum Junction Temperature	TJ	+150	°C
Maximum Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

RECOMMENDED OPERATING RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
High-Side Floating Absolute Voltage	VB	V _S +10 ~ V _S +20	V
High-Side Floating Supply Offset Voltage	Vs	600 (Note)	V
High-Side Floating Output Voltage	V _{HO}	$V_{S} \sim V_{B}$	V
Low-Side and logic Fixed Supply Voltage	Vcc	10 ~ 20	V
Low-Side Output Voltage	V _{LO}	0 ~ V _{CC}	V
Logic Input Voltage (HIN &LIN)	V _{IN}	0 ~ V _{CC}	V
Ambient Temperature	T _A	-40 ~ +125	°C

Note: Logic operational for V_S of -5V to +600V. Logic state held for V_S of -5V to -V_{BS}.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	125	°C/W



ELECTRICAL CHARACTERISTICS

 $[V_{BIAS} (V_{CC}, V_{BS})=15V$ and $T_A=25^{\circ}C$ unless otherwise specified. The V_{IN} , V_{TH} , and IIN parameters are referenced to COM. The V_0 and I_0 parameters are referenced to COM and are applicable to the respective output leads: HO or LO.]

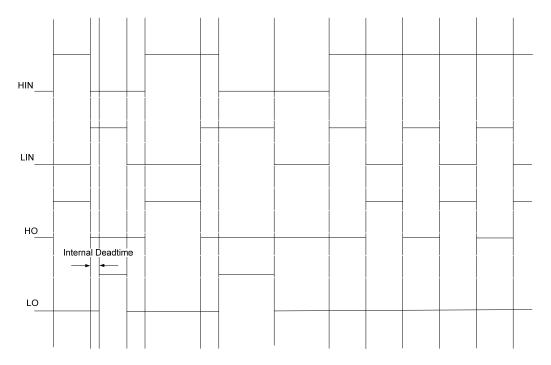
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Turn-ON Propagation Delay	t _{on}	V _S =0V		150	210	ns
Turn-OFF Propagation Delay	t _{OFF}	V _S =600V		150	210	ns
Turn-ON Rise Time	tr			70	120	ns
Turn-OFF Fall Time	t _f			35	60	ns
Delay matching, HS & LS Turn-ON/OFF	МТ				190	ns
Logic "1" (HIN) & Logic "0" (LIN) Input Voltage	VIH	V _{CC} =10V~20V	2.5			V
Logic "0" (HIN) & Logic "1" (LIN) Input Voltage	V _{IL}				0.8	V
High level Output Voltage, V_{BIAS} - V_{O}	V _{OH}	-1 -2m A		0.05	0.2	V
Low Level Output Voltage, Vo	V _{OL}	-I ₀ =2mA		0.02	0.1	V
Offset Supply Leakage Current	I _{LK}	$V_B = V_S = 600V$			50	μA
Quiescent V _{BS} Supply Current	I _{QBS}	I_{QBS} $(-0)(-5)(-5)(-5)(-5)(-5))$		60	150	μA
Quiescent V _{CC} Supply Current	l _{QCC}	-V _{IN} =0V or 5V		120	240	μA
Logic "1" Input Bias Current	ll _{N+}	V _{IN} =5V		5	40	μA
Logic "0" Input Bias Current	II _{N-}	V _{IN} =0V		1	5	μA
V _{CC} Supply Undervoltage Positive Going Threshold	V _{CCUV+}		8	8.9	9.8	V
V _{CC} Supply Undervoltage Negative Going Threshold	V _{CCUV-}		7.4	8.2	9	V
Output High Short Circuit Pulsed Current	I _{O+}	V _{IN} =0V, V _O =0V	60	290		mA
Output Low Short Circuit Pulsed Current	I _{O-}	P _W ≤10µs, V ₀ =15V	130	600		mA



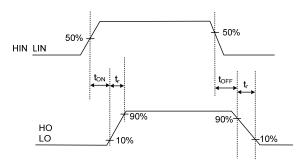
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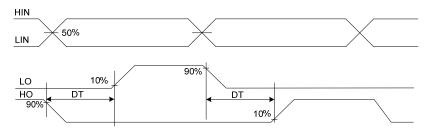
TEST CIRCUIT AND WAVEFORMS



INPUT/OUTPUT FUNCTIONALITY DIAGRAM



SWITCHING TIME WAVEFORMS



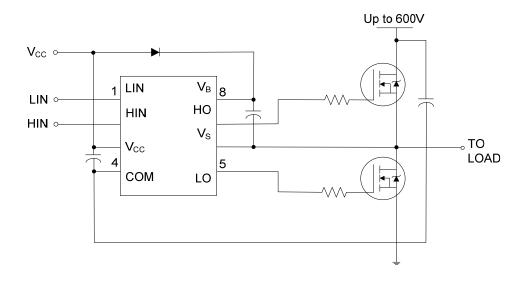
INTERANL DEADTIME TIMING



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TYPICAL APPLICATION CIRCUIT



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